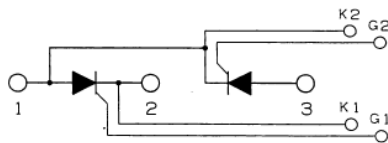


THYRISTOR

150A Avg 800 Volts

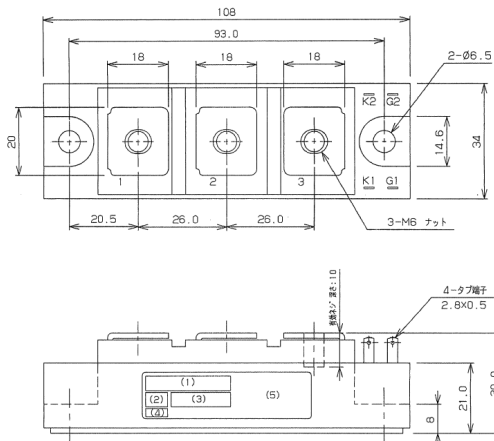
PDT1518

■回路図 CIRCUIT



■外形寸法図 OUTLINE DRAWING

Dimension: [mm]



■最大定格 Maximum Ratings

項目 Parameter	記号 Symbol	耐圧クラス Grade		単位 Unit
		PDT1518		
くり返しピークオフ電圧 Repetitive Peak Off-State Voltage	V_{DRM}	800		V
非くり返しピークオフ電圧 Non Repetitive Peak Off-State Voltage	V_{DSM}	900		V
くり返しピーク逆電圧 Repetitive Peak Reverse Voltage	V_{RRM}	800		V
非くり返しピーク逆電圧 Non Repetitive Peak Reverse Voltage	V_{RSM}	900		V

項目 Parameter	記号 Symbol	条件 Conditions	定格値	単位 Unit	
			Max. Rated Value		
平均オン電流 Average On-State Current	$I_{O(AV)}$	商用周波数 180° 通電 Half Sine Wave	$T_c = 76^\circ C$ 150	A	
実効オン電流 RMS On-State Current	I_{TRMS}		235	A	
サージオン電流 Surge On-State Current	I_{TSM}	50Hz 正弦半波, 1サージ, 非くり返し Half Sine Wave, 1Pulse, Non-Repetitive	3200	A	
電流二乗時間積 I Squared t	I^2t	2~10ms	51200	A ² s	
臨界オン電流上昇率 Critical Rate of Rise of Turned-On Current	di/dt	$V_D = 2/3 V_{DRM}$, $I_{TM} = 2 \cdot I_O$, $T_j = 125^\circ C$ $I_G = 300mA$, $di/dt = 0.2A/\mu s$	100	A/ μs	
ピークゲート電力損失 Peak Gate Power	P_{GM}		5	W	
平均ゲート電力損失 Average Gate Power	$P_{G(AV)}$		1	W	
ピークゲート電流 Peak Gate Current	I_{GM}		2	A	
ピークゲート電圧 Peak Gate Voltage	V_{GM}		10	V	
ピークゲート逆電圧 Peak Gate Reverse Voltage	V_{RGM}		5	V	
動作接合温度範囲 Operating Junction Temperature Range	T_{jw}		-40 ~ +125	°C	
保存温度範囲 Storage Temperature Range	T_{stg}		-40 ~ +125	°C	
絶縁耐圧 Isolation Voltage	V_{iso}	端子ーベース間, AC 1分間 Terminal to Base, AC 1min.	2500	V	
締付トルク Mounting Torque	ベース部 Mounting	F サマロソパ ウンド 塗布 Greased	M6	2.5 ~ 3.5	N·m
	主端子部 Terminal		M6	2.5 ~ 3.5	N·m

■ 電気的特性 Electrical Characteristics

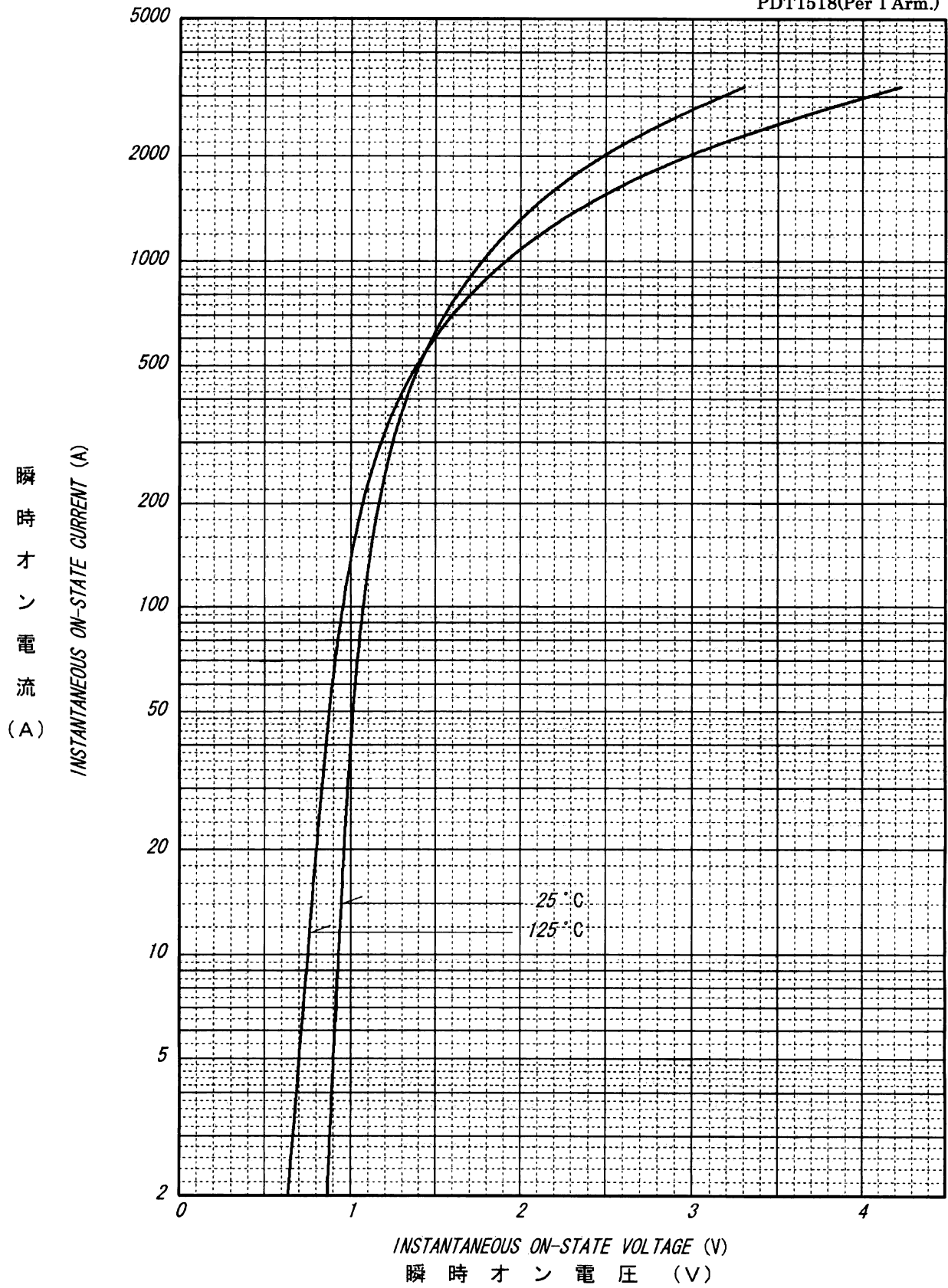
項目 Parameter	記号 Symbol	条件 Conditions	特性値 (最大) Maximum Value			単位 Unit
			最小 Min	標準 Typ	最大 Max	
ピークオフ電流 Peak Off-State Current	I_{DM}	$T_j = 125^\circ\text{C}$, $V_{DM} = V_{DRM}$			15	mA
ピーク逆電流 Peak Reverse Current	I_{RM}	$T_j = 125^\circ\text{C}$, $V_{RM} = V_{RRM}$			15	mA
ピークオン電圧 Peak Off-State Voltage	V_{TM}	$T_j = 25^\circ\text{C}$, $I_{TM} = 450\text{A}$			1.36	V
トリガゲート電流 Gate Current to Trigger	I_{GT}	$V_D = 6\text{V}$, $I_T = 1\text{A}$	$T_j = -40^\circ\text{C}$		300	mA
			$T_j = 25^\circ\text{C}$		150	
			$T_j = 125^\circ\text{C}$		80	
トリガゲート電圧 Gate Voltage to Trigger	V_{GT}	$V_D = 6\text{V}$, $I_T = 1\text{A}$	$T_j = -40^\circ\text{C}$		5	V
			$T_j = 25^\circ\text{C}$		3	
			$T_j = 125^\circ\text{C}$		2	
非トリガゲート電圧 Gate Non-Trigger Voltage	V_{GD}	$T_j = 125^\circ\text{C}$, $V_D = 2/3 V_{DRM}$	0.25			V
臨界オフ電圧上昇率 Critical Rate of Rise of Off-State Voltage	dv/dt	$T_j = 125^\circ\text{C}$, $V_D = 2/3 V_{DRM}$	500			V/ μs
ターンオフ時間 Turn-Off Time	t_q	$T_j = 125^\circ\text{C}$, $I_{TM} = I_o$, $V_D = 2/3 V_{DRM}$ $dv/dt = 20\text{V}/\mu\text{s}$, $V_R = 100\text{V}$, $-di/dt = 20\text{A}/\mu\text{s}$		100		μs
ターンオン時間 Turn-On Time	t_{gt}	$T_j = 25^\circ\text{C}$, $V_D = 2/3 V_{DRM}$ $I_G = 300\text{mA}$, $di_G/dt = 0.2\text{A}/\mu\text{s}$		6		μs
遅れ時間 Delay Time	t_d			2		μs
立ち上がり時間 Rise Time	t_r			4		μs
ラッチング電流 Latching Current	I_L		$T_j = 25^\circ\text{C}$		100	
保持電流 Holding Current	I_H	$T_j = 25^\circ\text{C}$		60		mA
熱抵抗 Thermal Resistance	$R_{th(j-c)}$	接合部-ケース間 Junction to Case			0.25	$^\circ\text{C}/\text{W}$
接触熱抵抗 Thermal Resistance	$R_{th(c-f)}$	ケースフィン間, サーマルコンパウンド塗布 Case to Fin, Greased			0.15	$^\circ\text{C}/\text{W}$

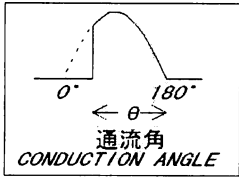
 質量 --- 約280 g
 Approximate Weight

1アーム当りの値 Value Per 1 Arm.

オン電圧特性
ON-STATE CURRENT VS. VOLTAGE

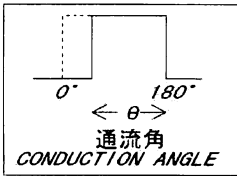
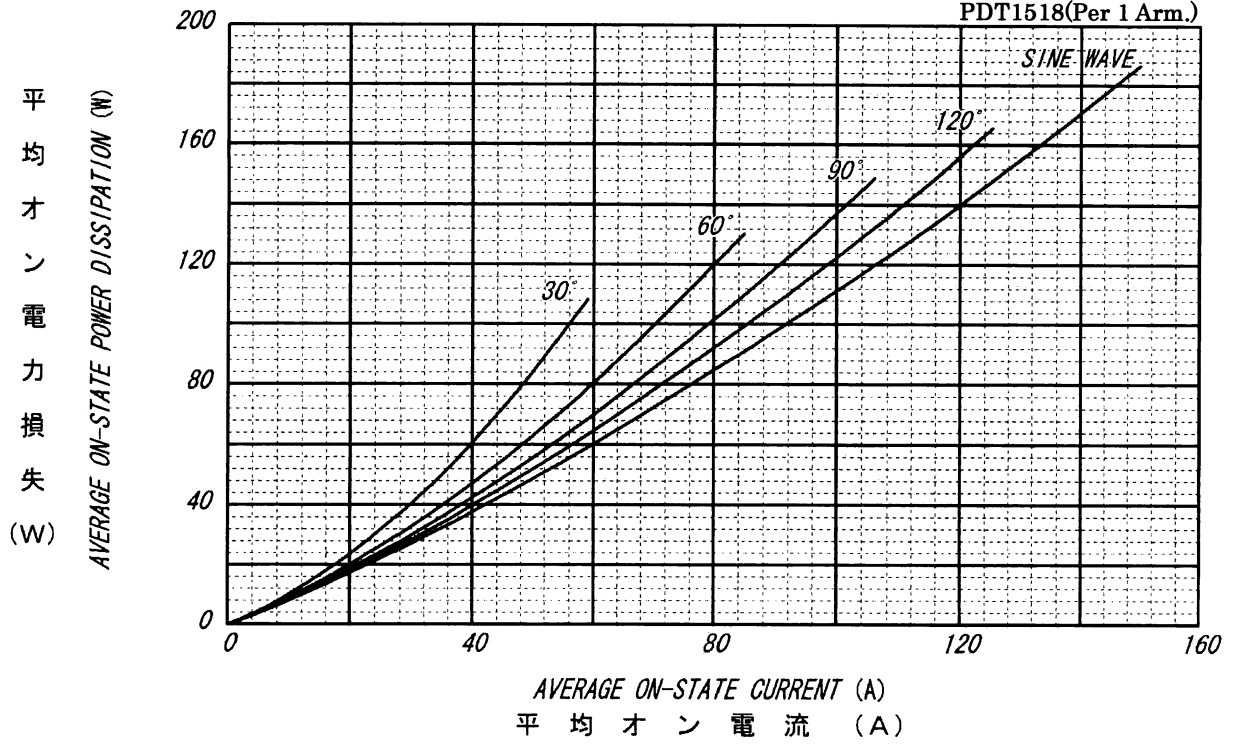
PDT1518(Per 1 Arm.)





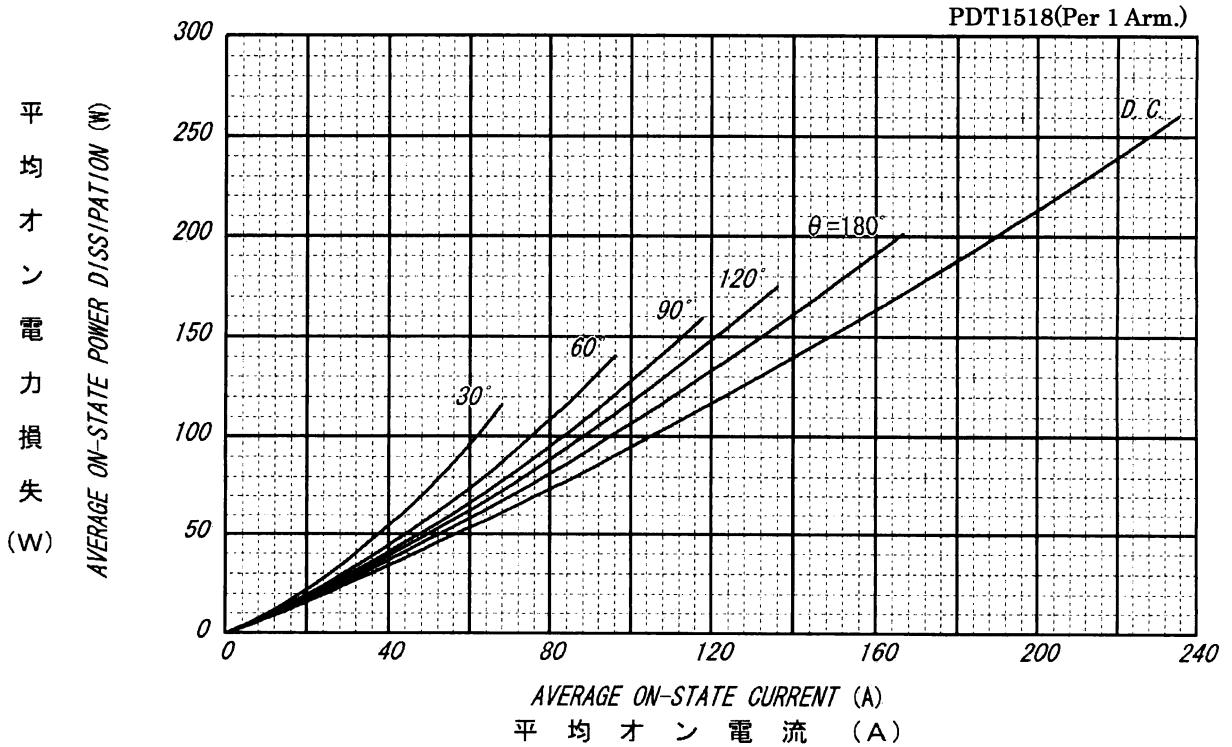
平均オン電力損失特性
AVERAGE ON-STATE POWER DISSIPATION

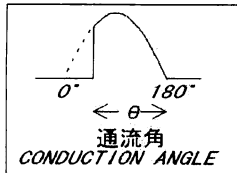
for SINUSOIDAL CURRENT WAVEFORM



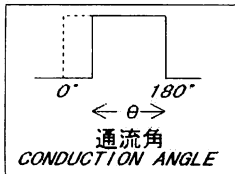
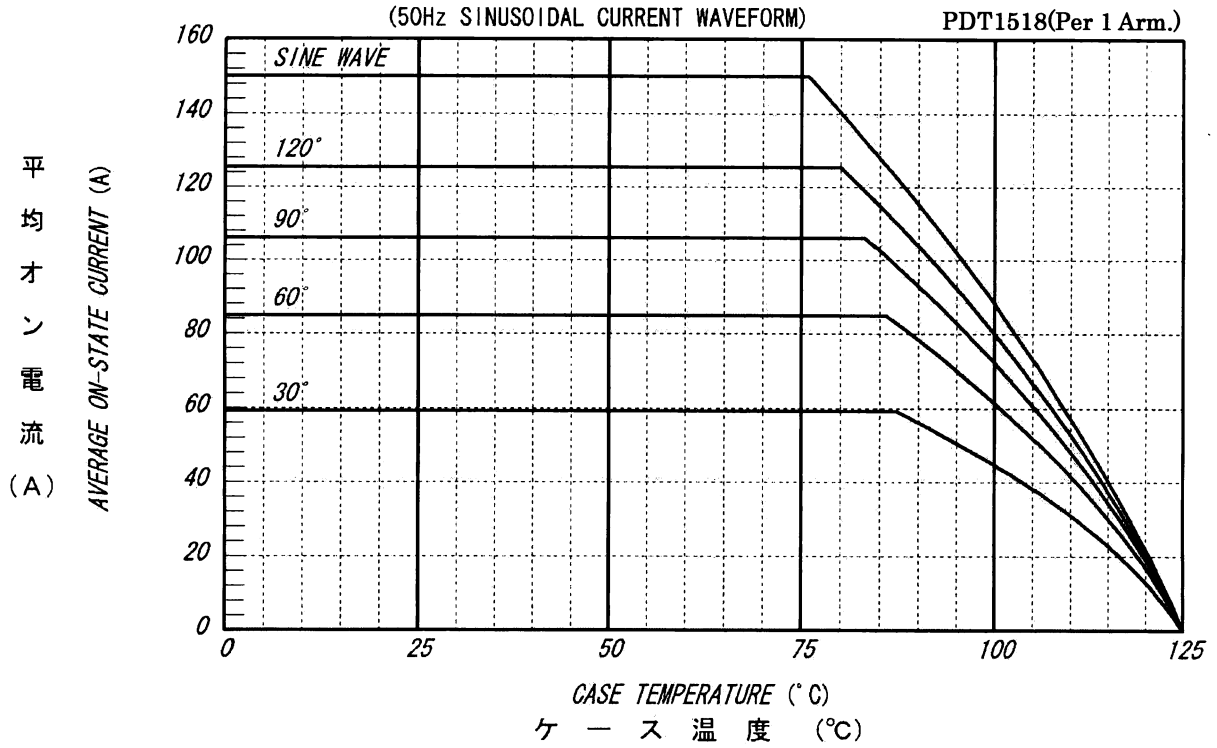
平均オン電力損失特性
AVERAGE ON-STATE POWER DISSIPATION

for RECTANGULAR CURRENT WAVEFORM

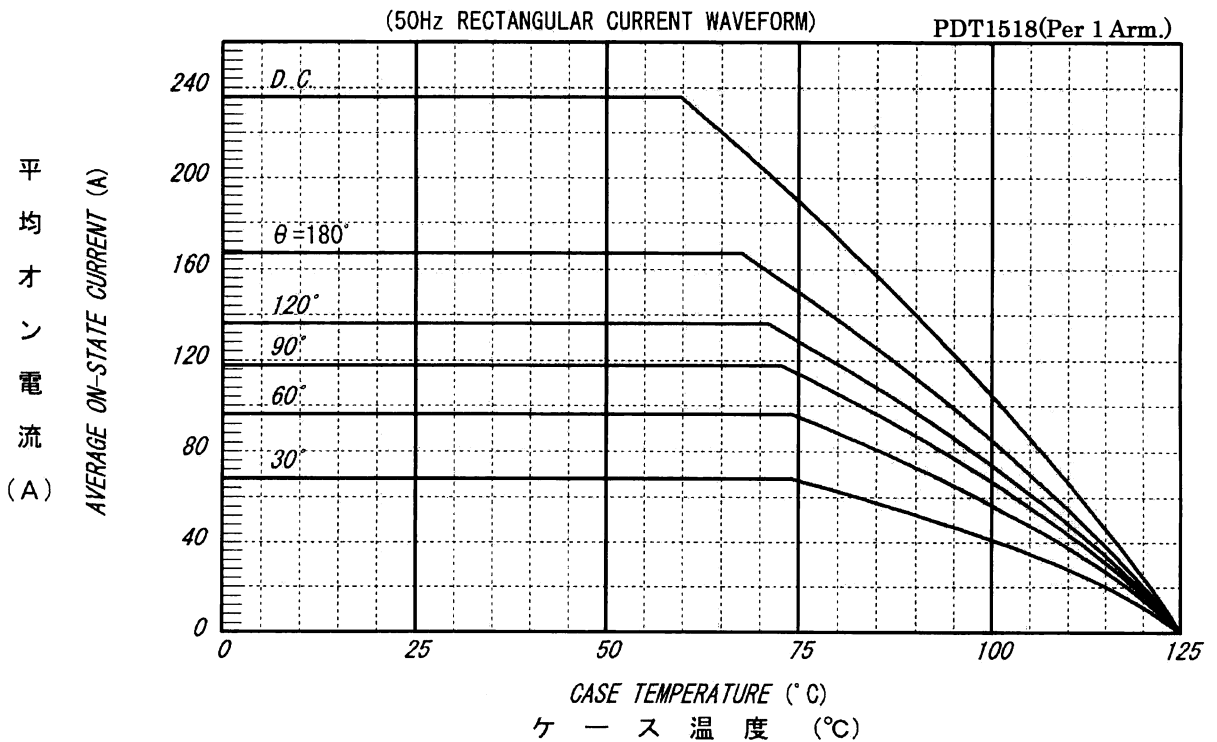




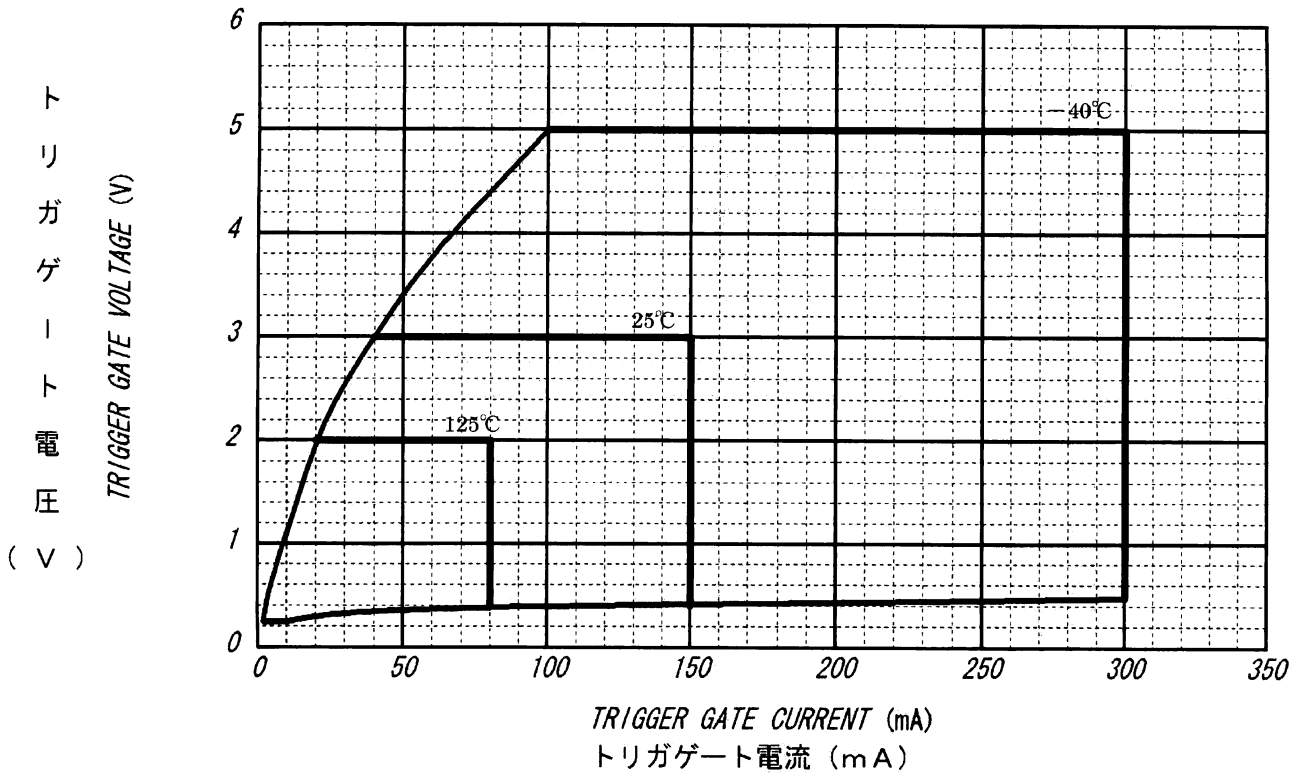
平均オン電流 - ケース温度定格
AVERAGE ON-STATE CURRENT VS. CASE TEMPERATURE



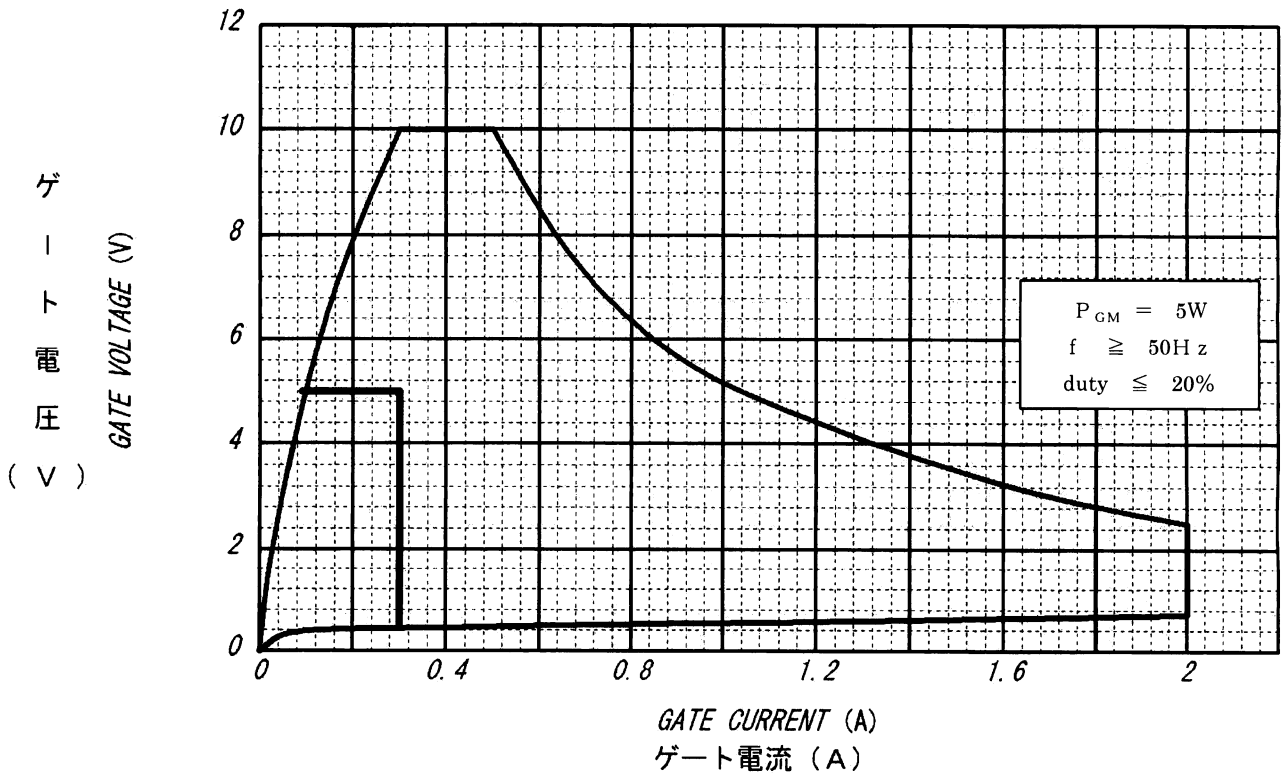
平均オン電流 - ケース温度定格
AVERAGE ON-STATE CURRENT VS. CASE TEMPERATURE



ゲート特性
GATE CHARACTERISTICS



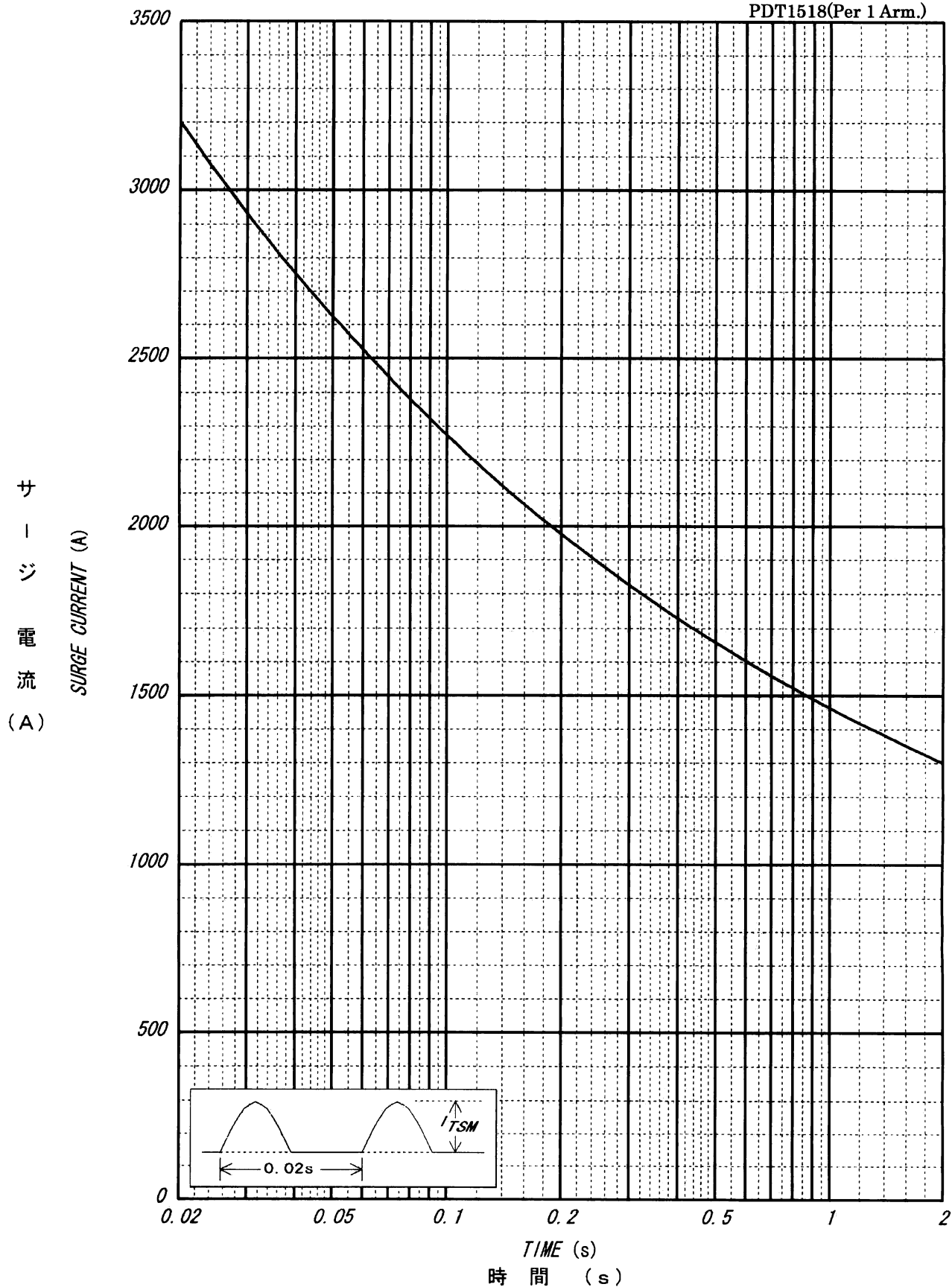
ゲート定格
GATE RATINGS



サージ電流定格 SURGE CURRENT RATINGS

f=50Hz, Half Sine Wave, Non-Repetitive, Tj=125°C

PDT1518(Per 1 Arm.)



過渡熱抵抗特性
 MAXIMUM TRANSIENT THERMAL IMPEDANCE

